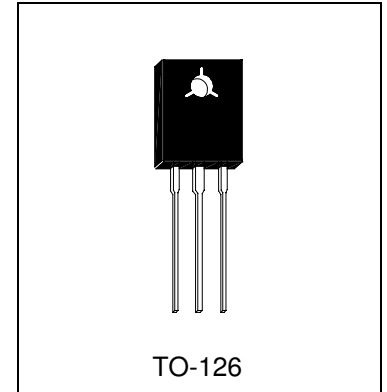




# HT882

NPN EPITAXIAL PLANAR TRANSISTOR



## Description

The HT882 is designed for using in output stage of 1w audio amplifier, voltage regulator, DC-DC converter and relay driver.

## Absolute Maximum Ratings (T<sub>A</sub>=25°C)

- Maximum Temperatures
  - Storage Temperature ..... -55 ~ +150 °C
  - Junction Temperature ..... +150 °C Maximum
- Maximum Power Dissipation
  - Total Power Dissipation (T<sub>A</sub>=25°C) ..... 1 W
  - Total Power Dissipation (T<sub>C</sub>=25°C) ..... 10 W
- Maximum Voltages and Currents
  - BV<sub>CBO</sub> Collector to Base Voltage ..... 40 V
  - BV<sub>CEO</sub> Collector to Emitter Voltage ..... 30 V
  - BV<sub>EBO</sub> Emitter to Base Voltage ..... 5 V
  - I<sub>C</sub> Collector Current (DC) ..... 3 A
  - I<sub>C</sub> Collector Current (Pulse) ..... 7 A
  - I<sub>B</sub> Base Current (DC) ..... 0.6 A

## Electrical Characteristics (T<sub>A</sub>=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV <sub>CBO</sub>	40	-	-	V	I <sub>C</sub> =100uA
BV <sub>CEO</sub>	30	-	-	V	I <sub>C</sub> =1mA
BV <sub>EBO</sub>	5	-	-	V	I <sub>E</sub> =10uA
I <sub>CBO</sub>	-	-	1	uA	V <sub>CB</sub> =30V
I <sub>EBO</sub>	-	-	1	uA	V <sub>EB</sub> =3V
*V <sub>CE(sat)</sub>	-	-	0.5	V	I <sub>C</sub> =2A, I <sub>B</sub> =0.2A
*V <sub>BE(sat)</sub>	-	1	2	V	I <sub>C</sub> =2A, I <sub>B</sub> =0.2A
*h <sub>FE1</sub>	30	150	-		I <sub>C</sub> =20mA, V <sub>CE</sub> =2V
*h <sub>FE2</sub>	100	200	500		I <sub>C</sub> =1A, V <sub>CE</sub> =2V
f <sub>T</sub>	-	90	-	MHz	I <sub>C</sub> =0.1A, V <sub>CE</sub> =5V
Cob	-	45	-	pF	V <sub>CB</sub> =10V, f=1MHz, I <sub>E</sub> =0

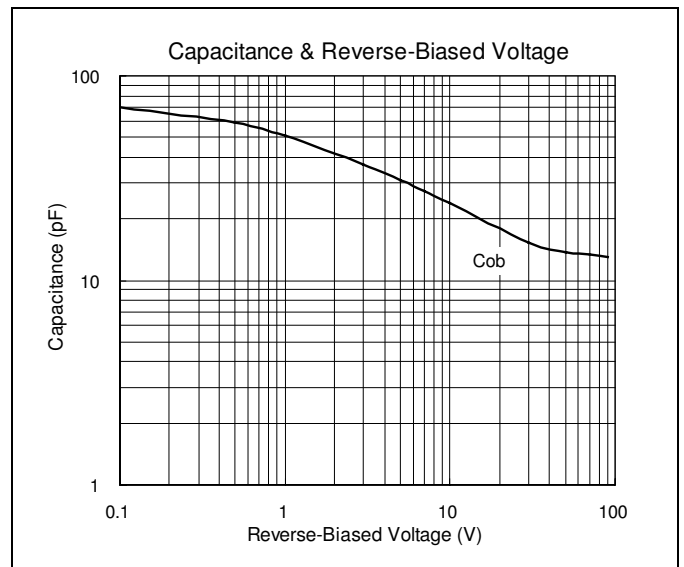
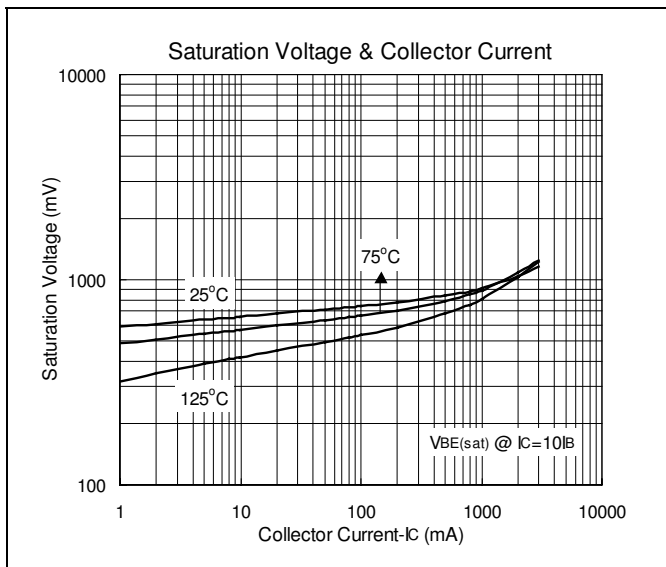
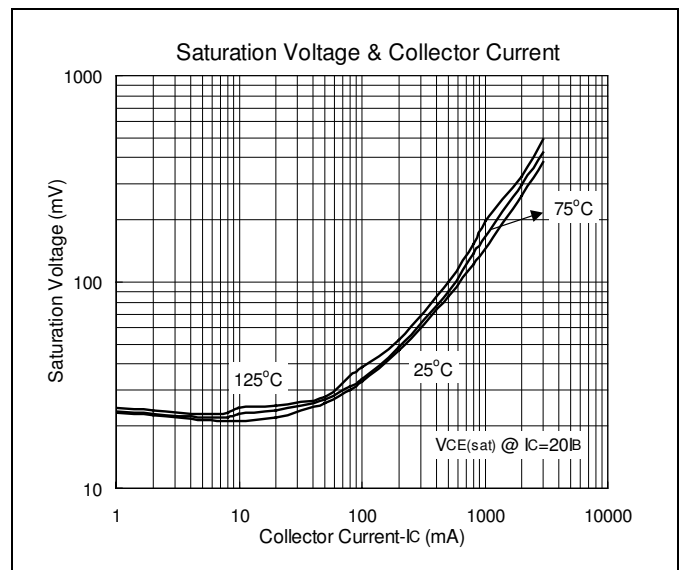
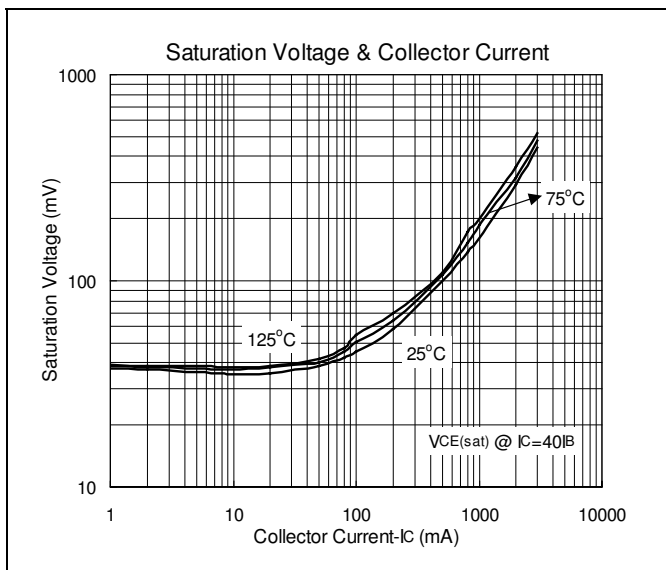
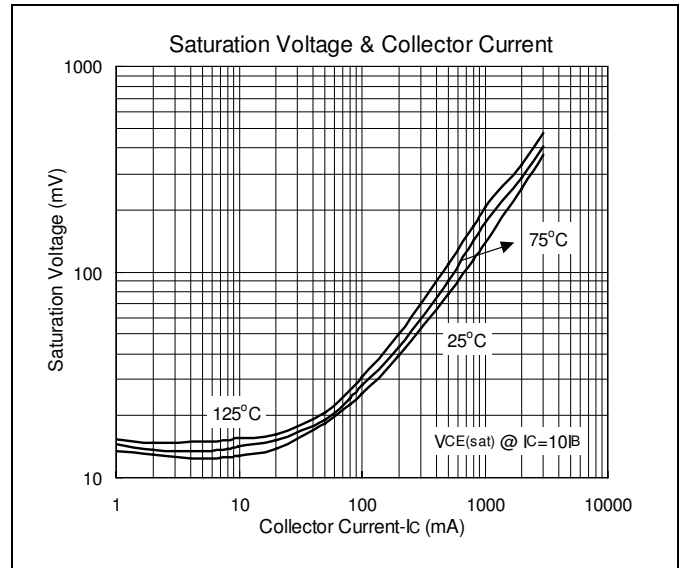
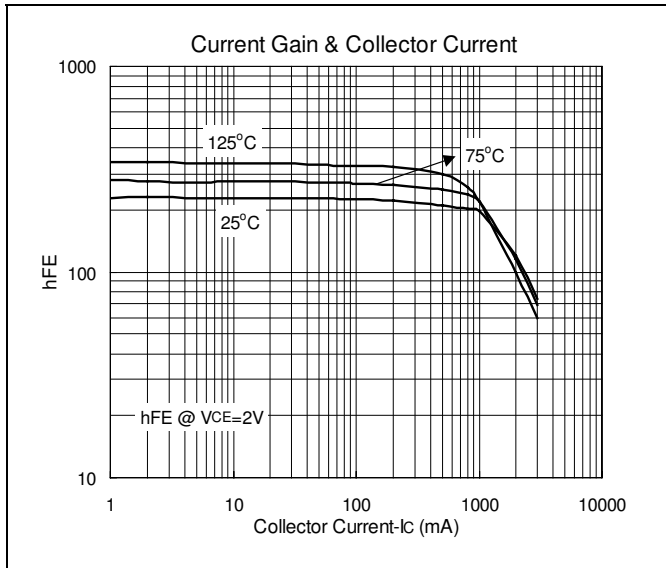
\*Pulse Test: Pulse Width ≤380us, Duty Cycle≤2%

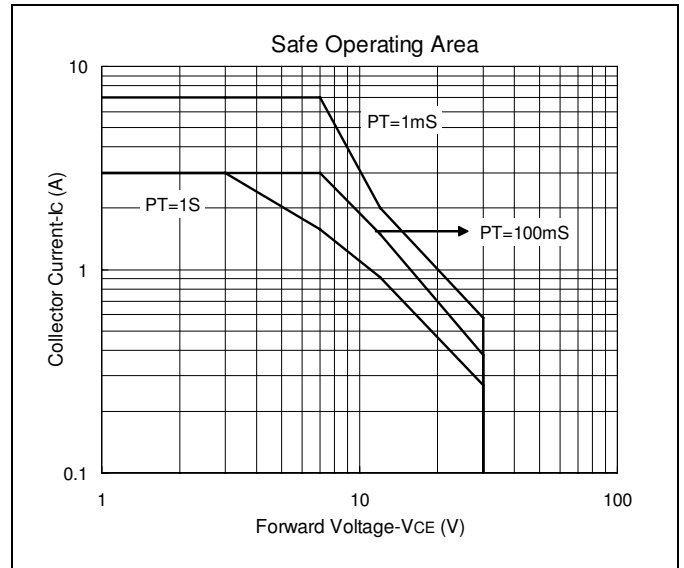
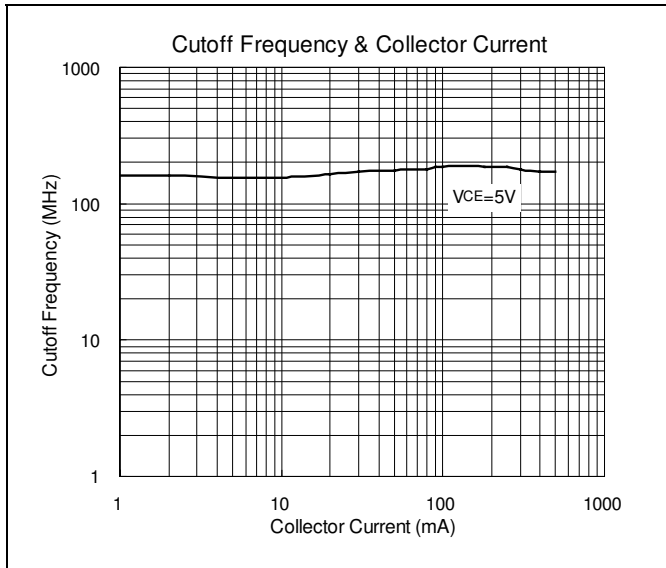
## Classification Of hFE2

Rank	Q	P	E
Range	100-200	160-320	250-500



### Characteristics Curve







### TO-126 Dimension

3-Lead TO-126  
 Plastic Package  
 HSMC Package Code: T

**Marking:**

Pb Free Mark  
 Pb-Free: "●" (Note)  
 Normal: None

Date Code: 8 8 2      Control Code: H T

**Note:** Green label is used for pb-free packing

**Pin Style:** 1.Emitter 2.Collector 3.Base

**Material:**

- Lead solder plating: Sn60/Pb40 (Normal), Sn/3.0Ag/0.5Cu or Pure-Tin (Pb-free)
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

DIM	Min.	Max.
A	3.60	4.40
B	6.90	7.60
C	13.00	16.50
D	7.20	8.50
F	0.65	0.88
G	1.00	1.42
H	4.52	4.62
J	1.14	1.50
K	0.90	1.50
L	0.45	0.60
M	2.92	3.40
N	2.00	2.70

Unit: mm

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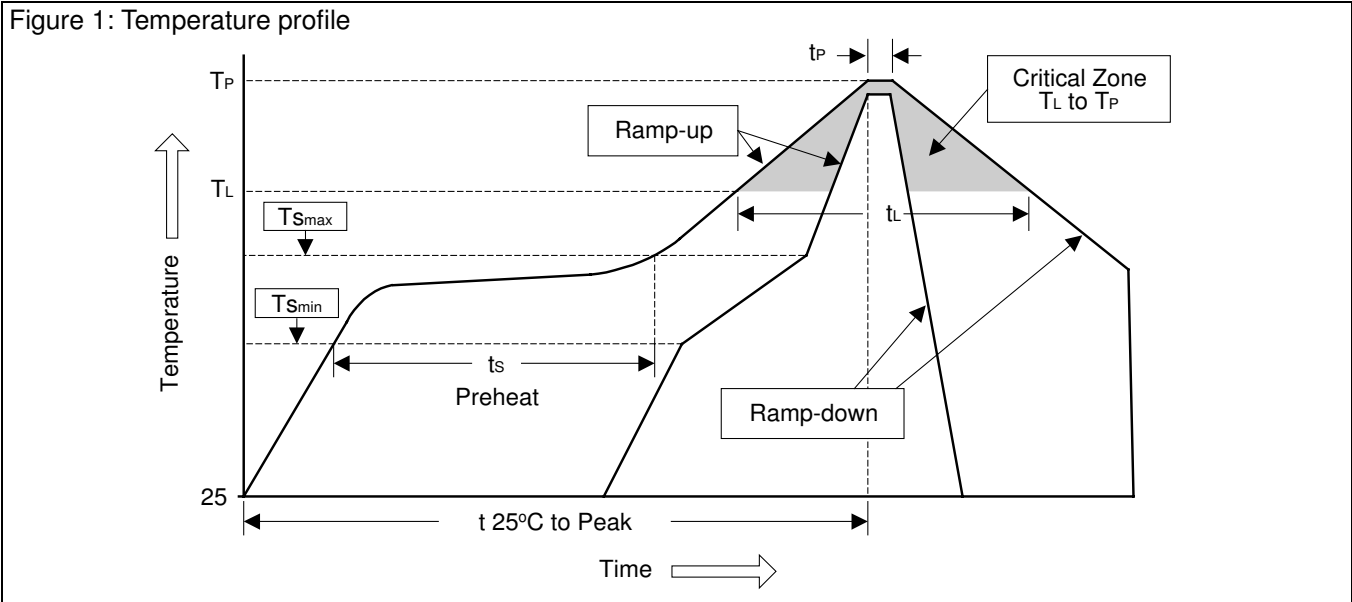
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 Tel: 886-3-5983621~5 Fax: 886-3-5982931



### Soldering Methods for HSMC's Products

1. Storage environment: Temperature=10°C~35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T <sub>L</sub> to T <sub>P</sub> )	<3°C/sec	<3°C/sec
Preheat		
- Temperature Min (T <sub>smin</sub> )	100°C	150°C
- Temperature Max (T <sub>smax</sub> )	150°C	200°C
- Time (min to max) (ts)	60~120 sec	60~180 sec
T <sub>smax</sub> to T <sub>L</sub>		
- Ramp-up Rate	<3°C/sec	<3°C/sec
Time maintained above:		
- Temperature (T <sub>L</sub> )	183°C	217°C
- Time (t <sub>L</sub> )	60~150 sec	60~150 sec
Peak Temperature (T <sub>P</sub> )	240°C +0/-5°C	260°C +0/-5°C
Time within 5°C of actual Peak Temperature (t <sub>p</sub> )	10~30 sec	20~40 sec
Ramp-down Rate	<6°C/sec	<6°C/sec
Time 25°C to Peak Temperature	<6 minutes	<8 minutes

### 3. Flow (wave) soldering (solder dipping)

Products	Peak temperature	Dipping time
Pb devices.	245°C ±5°C	5sec ±1sec
Pb-Free devices.	260°C +0/-5°C	5sec ±1sec